

Product Description

The PE4140 is an ultra-high linearity passive broadband Quad MOSFET array with high dynamic range performance capable of operation beyond 6.0 GHz. This quad array operates with differential signals at all ports (RF, LO, IF), allowing mixers to be built that use LO powers from -7 dBm to +20 dBm. Typical applications range from frequency up/down-conversion to phase detection for Cellular/PCS Base Stations, Wireless Broadband Communications and STB/Cable modems.

The PE4140 is manufactured on pSemi's UltraCMOS[™] process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate, offering the performance of GaAs with the economy and integration of conventional CMOS.

Figure 1. Functional Diagram



Table 1. AC and DC Electrical Specifications @ +25 °C

Symbol	Characteristics	Test Conditions	Min	Тур	Max	Units
F _{TYP}	Operating Frequency Range ¹		DC		6.0	GHz
V _{DS}	Drain-Source Voltage	$V_{GS} = +3V$, $I_{DS} = 40$ mA	260	320	380	mV
V _{DS} Match	Drain-Source Voltage Match			12	40	mV
V _T	Threshold Voltage	V _{DS} = 0.1V; per ASTM F617-00		-100		mV
R _{DS}	Drain-Source 'ON' Resistance	$V_{GS} = +3V$, $I_{DS} = 40$ mA	6.5	7.75	9.5	Ω

Note 1: Typical untested operating frequency range of Quad MOSFET transistors.

@2010.0000 = Comi Como All visibte veces

Ultra-High Linearity UltraCMOS™ Broadband Quad MOSFET Array

Features

- Ultimate Quad MOSFET array
- Ultra-high linearity, broadband performance beyond 6.0 GHz
- Ideal for mixer applications
- Up/down conversion
- Low conversion loss
- High LO Isolation
- Packaged in small 6-lead 3x3 mm DFN

Figure 2. Package Type 6-lead DFN







Figure 3. Pin Configuration (Top View)



Table 2. Pin Descriptions

Pin No.	Pin Name	Description
1	IF1	IF Output Connection (Drain)
2	RF1	RF Input Connection (Source)
3	RF2	RF Input Connection (Source)
4	LO2	LO Input Connection (Gate)
5	LO1	LO Input Connection (Gate)
6	IF2	IF Output Connection (Drain)

Table 3. Absolute Maximum Ratings

Symbol	Parameters/ Conditions	Min	Max	Units
T _{st}	Storage temperature range	-65	150	°C
T _{OP}	Operating temperature range	-40	85	°C
$V_{\text{DC + AC}}$	Maximum DC plus peak AC voltage across Drain- Source		±3.3	v
$V_{\text{DC+AC}}$	Maximum DC plus peak AC voltage across Gate- Drain or Gate-Source		±4.2	v
V _{ESD}	HBM ¹ ESD Voltage		100	V

Note 1: ML_STD 883 Method 3015.7

Exceeding absolute maximum ratings may cause permanent damage. Operation should be restricted to the limits in the Operating Ranges table. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

Electrostatic Discharge (ESD) Precautions

This MOSFET device has minimally protected inputs and is highly susceptible to ESD damage. When handling this UltraCMOS[™] device, observe the same precautions that you would use with other ESD-sensitive devices.

Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS[™] devices are immune to latch-up.

Device Description

The PE4140 passive broadband Quad MOSFET array is designed for use in up-conversion and down-conversion applications for high performance systems such as cellular infrastructure equipment and STB/CATV systems.

The PE4140 is an ideal mixer core for a wide range of mixer products, including module level solutions that incorporate baluns or other singleended matching structures enabling three-port operation.

The performance level of this passive mixer is made possible by the very high linearity afforded by pSemi's UltraCMOS[™] process.

Marking

Packaged devices are marked with part number "4140", date code and lot code.

Moisture Sensitivity Level

The Moisture Sensitivity Level rating for the PE4140 in the 6-lead 3x3 DFN package is MSL1.



Evaluation Kit Figure 4. Evaluation Board Layout

pSemi Specification 101/0090





Applications Support

If you have a problem with your evaluation kit or if you have applications questions, please contact applications support:

E-Mail: help@psemi.com (fastest response) Phone: (858) 731-9400

Figure 5. Evaluation Board Schematic

pSemi Specification 102/0115



Note: This is the complete evaluation board schematic; which can be used for multiple configurations. Not all components need be populated. Refer to 'typical schematics' on following pages.



Figure 6. Typical Schematic for a PCS Application



 Table 4. Typical Performance in a PCS Application @ +25 °C

Parameter	Minimum	Typical	Maximum	Units
Frequency Range**				
LO	1630		2130	MHz
RF	1700		2200	MHz
IF		70		MHz
Conversion Loss**		9.5		dD
(Includes balun losses)		0.0		uВ
Isolation**				
LO-RF		36		dB
LO-IF		26		dB
Input IP3**		32		dBm
Input 1 dB Compression**		22		dBm

** Data taken on an Evaluation Board narrow-band tuned to cover the PCS band, IF = 73MHz low-side, LO drive = 17dBm.



Typical Performance Plots in a PCS Application @ +25 °C (LO=17 dBm, IF=73 MHz Low-side)

Figure 7. IIP3 vs. Frequency

Figure 8. Conversion Loss vs. Frequency





Figure 9. LO-RF & LO-IF Isolation





Figure 10. Typical Schematic for a CATV Application



Note: L1 and L2 provide LO port matching for optimum performance. Typical gate capacitance is approximately 2.5 pF.

Table 5. Typical Performance in a CATV Application @ +25
--

Parameter	Minimum	Typical	Maximum	Units
Frequency Range**				
LO	1116		1926	MHz
RF	54		864	MHz
IF		1062		MHz
Conversion Loss**		6 5		dB
(Includes balun losses)		0.5		uв
Isolation**				
LO-RF		40		dB
LO-IF		28		dB
Input IP3**		23		dBm
Input 1 dB Compression**		13		dBm

** Data taken on an Evaluation Board tuned for a broadband CATV application, IF = 1062 MHz, RF drive = -5 dBm, LO drive = 10 dBm.



Typical Performance Plots in a CATV Application @ +25 °C

Figure 11. IIP3 vs. Frequency



Figure 12. Conversion Loss vs. Frequency



Figure 13. LO-RF & LO-IF Isolation





Figure 14. Package Drawing

6-lead DFN



0.350±0.050 0.350±0.050 0.350±0.050 0.250±0.050 Exp. DAP 2.000±0.050 Exp. DAP 2.000±0.050 Exp. DAP 0.250±0.050 0.250±0.050 0.250±0.050 0.250±0.050

<u>NDTE:</u>

IN ISEP AND SEP SHARE THE SAME EXHIBE DUILINE BUT WITH DIFFEPENT THICKNESS:

		TSLP	SLP
_	MAX.	0.800	0.900
A	NUM.	ແ./ວເ	ა.გეი
	MIN.	n,7nn	<u> </u>



NOTE: The exposed solder pad (on the bottom of the package) is not electrically connected to any other pin (isolated).

Figure 15. Marking Specifications



Device

Figure 16. Tape and Reel Specifications

6-lead DFN



Table 6. Dimensions

Dimension	DFN 3x3 mm
Ao	3.23 ± 0.1
Во	3.17 ± 0.1
Ko	1.37 ± 0.1
Р	4 ± 0.1
W	8 +0.3, -0.1
Т	0.254 ± 0.02
R7 Quantity	3000
R13 Quantity	N.A.

Note: R7 = 7 inch Lock Reel, R13 = 13 inch Lock Reel

NOTES:

1. 10 SPROCKET HOLE PITCH CUMULATIVE TOLERANCE ±0.2

Device Orientation in Tape

- 2. EAMBER IN COMPLIANCE WITH EIA 481
- 3. POCKET POSITION RELATIVE TO SPROCKET HOLE MEASURED AS TRLE POSITION OF POCKET, NOT POCKET HOLE



Table 7. Ordering Infomation

Order Code	Part Marking	Description	Package	Shipping Method
PE4140B-Z	4140	PE4140G-06DFN 3x3mm-3000C	Green 6-lead 3x3 mm DFN	3000 units / T&R
EK4140-01	PE4140-EK	PE4140-06DFN 3x3mm-EK	Evaluation Kit	1 / Box

Sales Contact and Information

For additional information, contact Sales at <u>sales@psemi.com</u>.

<u>Advance Information</u>: The product is in a formative or design stage. The datasheet contains design target specifications for product development. Specifications and features may change in any manner without notice. <u>Preliminary Specification</u>: The datasheet contains preliminary data. Additional data may be added at a later date. pSemi reserves the right to change specifications at any time without notice in order to supply the best possible product. <u>Product Specification</u>: The datasheet contains final data. In the event pSemi decides to change the specifications, pSemi will notify customers of the intended changes by issuing a CNF (Customer Notification Form).

The information in this document is believed to be reliable. However, pSemi assumes no liability for the use of this information. Use shall be entirely at the user's own risk.

©2018-2020 pSemi Corp. All rights reserved.

No patent rights or licenses to any circuits described in this document are implied or granted to any third party. pSemi's products are not designed or intended to support or sustain life, or for use in any application in

pSemi's products are not designed or intended to support or sustain life, or for use in any application in which the failure of the pSemi product could create a situation in which personal injury or death might occur. pSemi assumes no liability for damages, including consequential or incidental damages, arising out of the use of its products in such applications.

The Peregrine Semiconductor name, Peregrine Semiconductor logo and UltraCMOS are registered trademarks and the pSemi name, pSemi logo, HaRP and DuNE are trademarks of pSemi Corporation in the U.S. and other countries.

pSemi products are protected under one or more of the following U.S. patents: patents.psemi.com.

Document No. DOC-87599-3 | UltraCMOS[™] RFIC Solutions

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for RF Mixer category:

Click to view products by pSemi manufacturer:

Other Similar products are found below :

HMC337-SX mamx-009646-23dbml HMC339-SX CHR3664-QEG HMC8192-SX MIQ24MS-2 HMC220BMS8GETR M85C HMC554A-SX HMC8192LG HMC521A-SX HMC521ACHIPS CMD258C4 CMD258 LT5511EFE MAMX-011023-SMB HMC399MS8TR HMC333TR HMC214MS8TR HMC175MS8TR HMC1043LC3TR MAMXSS0012TR-3000 109728-HMC129LC4 CSM1-13 SA612AD/01.112 HMC785LP4ETR LT5579IUH#PBF HMC773ALC3BTR HMC329ALC3B MY63H AD8343ARUZ-REEL7 AD608AR AD608ARZ AD831APZ AD831APZ-REEL7 AD8342ACPZ-REEL7 AD8343ARUZ AD8344ACPZ-REEL7 ADL5350ACPZ-R7 ADL5363ACPZ-R7 ADL5365ACPZ-R7 ADL5802ACPZ-R7 HMC1056LP4BE HMC1057-SX HMC1063LP3E HMC1081-SX HMC1093-SX HMC1106-SX HMC129 HMC143